

LASER DIODE FOLD-785-100S-VBG

FOLD-785-100S-VBG is a single mode semiconductor laser diode with 100mW CW output power at 785nm. Due to the integrated VBG the wavelength is fixed and the spectral width is very narrow. It is suitable for the use in various opto-electronic applications.

APPLICATIONS:

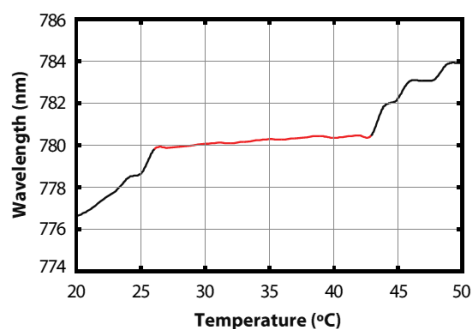
- Raman Spectroscopy
- Bio-Instrumentation
- Metrology
- Sensing
- Analytical Instrumentation

Optical and electrical characteristics (T = 25°C, P = 100mW):

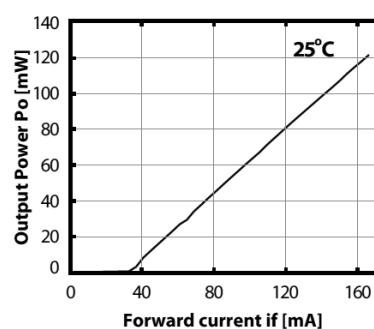
Operating Parameters	Symbol	Min	Typ	Max	Unit
Optical Power	P _{out}	-	-	100	mW
Wavelength	λ	784	785	786	nm
Line Width	Δλ	-	175	-	MHz
Threshold Current	I _{th}	-	50	-	mA
Forward Current	I _f	-	130	200	mA
Forward Voltage	V _f	-	1.3	2.2	V
Reverse Voltage	V _r	-	-	2	V
Slope Efficiency	ΔP/ΔI	-	0.9	-	mW/mA
Beam Divergence, Perpendic.	Θ _⊥	-	25	-	°
Beam Divergence, Parallel	Θ	-	10	-	°
Operating Temperature	T _{op}	0	-	40	°C
Central Stabilized Temperature	T _c	15	-	35	°C
Stabilized Temperature Range	T _r	15	-	-	°C
Storage Temperature	T _s	-20	-	70	°C
Emitter Size	E _s	1.5 x 3			μm
Coherence Length	> 1m				
Polarization Orientation	TE				

PERFORMANCE AND PACKAGE SPECIFICATION

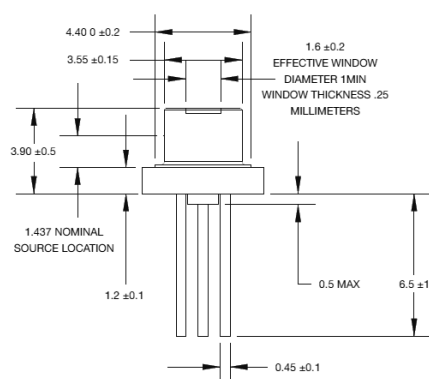
Stabilized Temperature Range



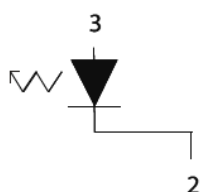
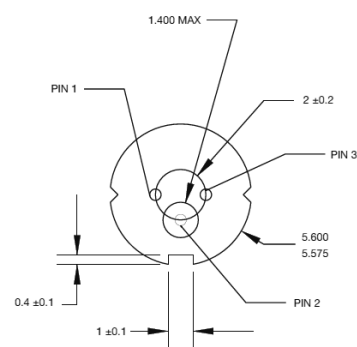
Output Power vs Forward Current (Typical)



Side View



Bottom View



1
°

Pinout	
1	Not Connected
2	Case
3	LD Anode